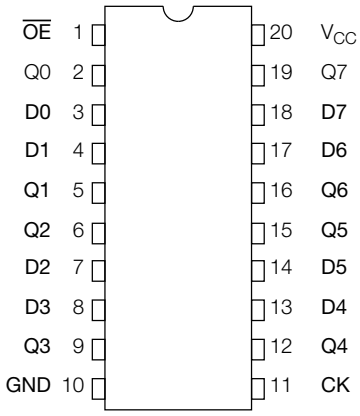
Features:

- **High Speed:** f_{MAX} = 180MHz (typ.) at V_{CC} = 5V
- **Low Power Dissipation:** I_{CC} = 8μA (max.) at Ta = 25°C
- **Compatible with TTL Outputs:** V_{IL} = 0.8V (max.); V_{IH} = 2.0V (min.)
- **Symmetrical Output Impedance:** $|I_{OH}|$ = I_{OL} = 24mA (min.). Capability of driving 50Ω transmission lines.
- **Balanced Propagation Delays:** t_{pLH} = t_{pHL}
- **Pin and Function Compatible with 74F374**
- **ACT374 Available in DIP, SOIC, SOP and SSOP Packages**

Pin Assignment

TC74ACT374



The TC74ACT374 is an advanced high speed CMOS OCTAL FLIP-FLOPS with 3-STATE OUTPUT fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL, while maintaining the CMOS low power dissipation.

This device may be used as a level converters for interfacing TTL or NMOS to high speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and a output enable input ($\overline{OE}$).

When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

The TC74ACT374 has non-inverting outputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

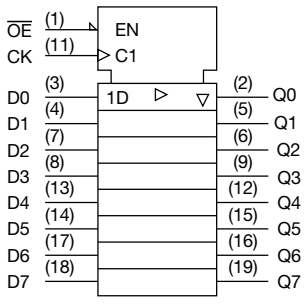
Truth Table

INPUTS			OUTPUTS
$\overline{OE}$	CK	D	Q(374)
H	X	X	Z
L	↓	X	Q_n
L	↑	L	L
L	↑	H	H

X: Don't Care
Z: High Impedance
Q_n ($\overline{Q}_n$): No Change

IEC Logic Symbol

TC74ACT374



Absolute Maximum Ratings

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~V_{CC} + 0.5	V
DC Output Voltage	V_{OUT}	-0.5~V_{CC} + 0.5	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±50	mA
DC Output Current	I_{OUT}	±50	mA
DC V_{CC}/Ground Current	I_{CC}	±200	mA
Power Dissipation	P_D	500 (DIP) */180 (SOP)	mW
Storage Temperature	T_{stg}	-65~150	°C
Lead Temperature 10sec	T_L	300	°C

* 500mW in the range of Ta = -40°C~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

Recommended Operating Conditions

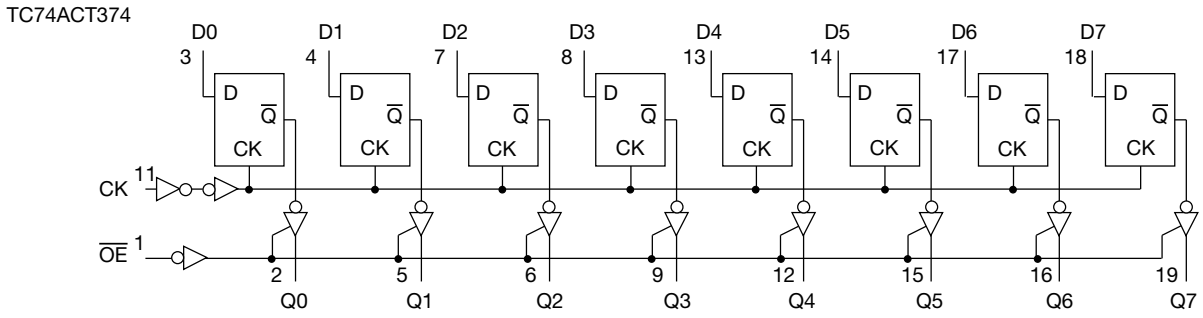
PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~V_{CC}	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	dt/dv	0~10	ns/v

DC Electrical Characteristics

PARAMETER	SYMBOL	TEST CONDITION		V_{CC}	Ta = 25°C Min.	Ta = 25°C Typ.	Ta = 25°C Max.	Ta = -40~85°C Min.	Ta = -40~85°C Max.	UNIT
High-Level Input Voltage	V_{IH}	—		4.5~5.5	2.0	—	—	2.0	—	V
Low-Level Input Voltage	V_{IL}	—		4.5~5.5	—	—	0.8	—	0.8	V
High-Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -50μA	4.5	4.4	4.5	—	4.4	—	V
			I_{OH} = -24mA	4.5	3.94	—	—	3.80	—	
			I_{OH} = -75mA*	5.5	—	—	—	3.85	—	
Low-Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA	4.5	—	0.0	0.1	—	0.1	V
			I_{OL} = 24mA	4.5	—	—	0.36	—	0.44	
			I_{OL} = 75mA*	5.5	—	—	—	—	1.65	
3-State Output Off-State Current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		5.5	—	—	±0.5	—	±5.0	μA
Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		5.5	—	—	±0.1	—	±1.0	
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	8.0	—	80.0	
	ΔI_{CC}	Per input: V_{CC} = 3.4V Other input: V_{CC} or GND		5.5	—	—	1.35	—	1.5	mA

* This spec indicates the capability of driving 50Ω transmission lines.
One output should be tested at a time for a 10ms maximum duration.

System Diagram



Timing Requirements (Input $t_r = t_f = 3n$)

PARAMETER	SYMBOL	TEST CONDITION		Ta=25°C		Ta= −40~85°	UNIT
			V_{CC}	Typ.	Max.	Max.	
Minimum Pulse Width (CK)	$t_{W(H)}$ $t_{W(L)}$	—	5.0±0.5	—	5.0	5.0	ns
Minimum Set-up Time	t_s	—	5.0±0.5	—	3.0	3.0	
Minimum Hold Time	t_h	—	5.0±0.5	—	2.0	2.0	

AC Electrical Characteristics (C_L = 50pF, R_L = 500Ω, Input $t_r = t_f$ = 3ns)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT
			V_{CC}	Min.	Typ.	Max.	Min.	Max.	
Propagation Delay Time (CK–Q, $\overline{Q}$)	t_{pLH} t_{pHL}	—	5.0±0.5	—	6.1	9.6	1.0	11.0	ns
Output Enable Time	t_{pZL} t_{pZH}	—	5.0±0.5	—	6.2	10.1	1.0	11.5	
Output Disable Time	t_{pLZ} t_{pHZ}	—	5.0±0.5	—	5.6	7.9	1.0	9.0	
Maximum Clock Frequency	f_{MAX}	—	5.0±0.5	95	160	—	95	—	MHz
Input Capacitance	C_{IN}	—	—	—	5	10	—	10	pF
Output Capacitance	C_{OUT}	—	—	—	10	—	—	—	
Power Dissipation Capacitance	C_{PD} [1]	—	—	—	34	—	—	—	

Note (1): C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation: $I_{CC\ (opr)} = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC} / 8$ (per F/F).
And the total C_{PD} when n pcs. of Flio-Flop operate can be gained by the following equation: C_{PD} (total)=22+12 • n.